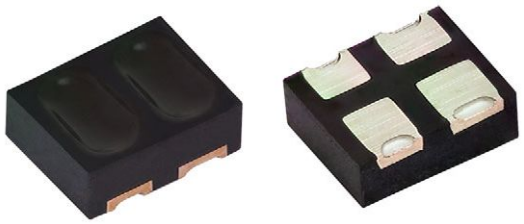
Reflective Optical Sensor with Transistor Output



FEATURES

- Package type: SMD
- Detector type: phototransistor
- Dimensions (L x W x H in mm): 2.5 x 2 x 0.8
- Operating range within > 20 % relative collector current: 0.2 mm to 2.5 mm
- Emitter wavelength: 940 nm
- Moisture sensitivity level (MSL): 4
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

Pb-free

e2

RoHS COMPLIANT

HALOGEN FREE

DESCRIPTION

The VCNT2020 is a reflective sensor in a miniature SMD package. It has a compact construction where the emitting light source and the detector are arranged in the same plane. The operating infrared wavelength is 940 nm. The detector consists of a silicon phototransistor. The sensor analog output signal (photo current) is triggered by detection of reflected infrared light from a close by object.

The sensor has a built in daylight blocking filter, which greatly suppresses disturbing ambient light and therefore increases signal to noise ratio.

APPLICATIONS

- Position sensor
- Optical switch
- Optical encoder (e.g. disc and tape drives for DVD and / or camera applications)
- Object detection (e.g. paper presence in printer and copy machines)

PRODUCT SUMMARY

PART NUMBER	DISTANCE FOR MAXIMUM CTR_{rel} (1) (mm)	DISTANCE RANGE FOR RELATIVE I_{out} > 20 % (mm)	TYPICAL OUTPUT CURRENT UNDER TEST (2) (mA)	DAYLIGHT BLOCKING FILTER INTEGRATED
VCNT2020	0.5	0.2 to 2.5	1.6	Yes

Notes

(1) CTR: current transfer ratio, I_{out}/I_{in}

(2) Conditions like in table basic characteristics/sensors

ORDERING INFORMATION

ORDERING CODE	PACKAGING	VOLUME (1)	REMARKS
VCNT2020	Tape and reel	MOQ: 3000 pcs	Drypack, MSL 4

Note

(1) MOQ: minimum order quantity

ABSOLUTE MAXIMUM RATINGS (T_{amb} = 25 °C, unless otherwise specified)

PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT
INPUT (EMITTER)				
Reverse voltage		V_R	5	V
Forward current		I_F	100	mA
Forward surge current	$t_p \leq 100$ µs	I_{FSM}	500	mA
OUTPUT (DETECTOR)				
Collector emitter breakdown voltage		$V_{(BR)CEO}$	20	V
Emitter collector voltage		V_{ECO}	7	V
Collector current		I_C	20	mA
SENSOR				
Total power dissipation	$T_{amb} \leq 25$ °C	P_{tot}	170	mW
Ambient temperature range		T_{amb}	-25 to +85	°C
Storage temperature range		T_{stg}	-25 to +85	°C
Soldering temperature	In accordance with Fig. 11	T_{sd}	260	°C

ABSOLUTE MAXIMUM RATINGS

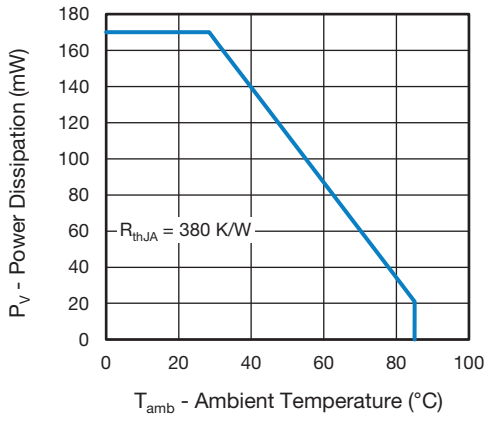


Fig. 1 - Power Dissipation vs. Ambient Temperature

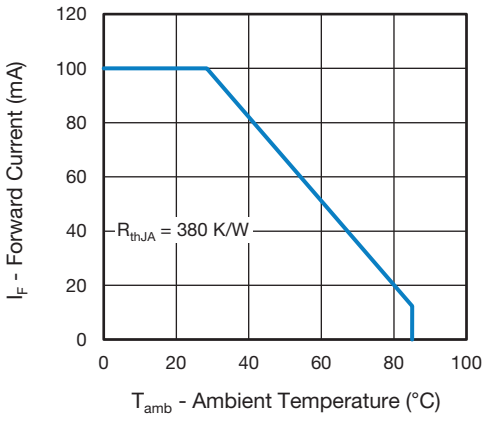


Fig. 2 - Forward Current vs. Ambient Temperature

BASIC CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)						
PARAMETER	**TEST CONDITION**	**SYMBOL**	**MIN.**	**TYP.**	**MAX.**	**UNIT**
INPUT (EMITTER)						
Forward voltage	I_F = 20 mA	V_F	-	1.25	1.4	V
	I_F = 100 mA		-	1.5	1.7	
Temperature coefficient of V_F	I_F = 20 mA	TKV_F	-	-1.0	-	mV/K
Peak wavelength	I_F = 100 mA	λ_P	-	940	-	nm
Reverse current	V_R = 5 V	I_R	-	-	10	µA
OUTPUT (DETECTOR)						
Collector emitter breakdown voltage	I_C = 0.1 mA, E = 0	$V_{(BR)CEO}$	20	-	-	V
Emitter collector voltage	I_E = 100 µA, E = 0	V_{ECO}	7	-	-	V
Collector emitter dark current	V_{CE} = 5 V, E = 0	I_{CEO}	-	1	100	nA
SENSOR						
Collector current	V_{CE} = 5 V, I_F = 20 mA, d = 1 mm	I_C	0.5	1.6	3.5	mA
Current transfer ratio	I_C/I_F, d = 1 mm, V_{CE} = 5 V	CTR	-	8	-	%
Rise time	I_C = 0.8 mA, V_{CE} = 5 V, R_L = 100 Ω	t_r	-	10	70	µs
Fall time	I_C = 0.8 mA, V_{CE} = 5 V, R_L = 100 Ω	t_f	-	15	70	µs

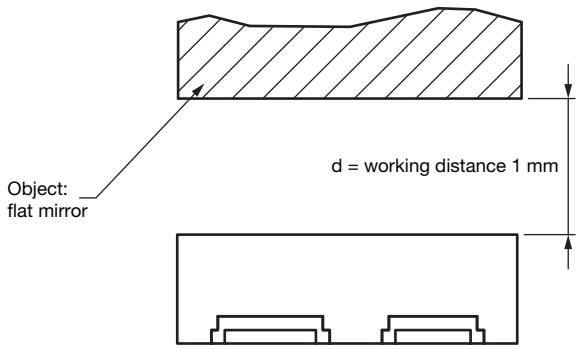


Fig. 3 - Test Circuit

BASIC CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)

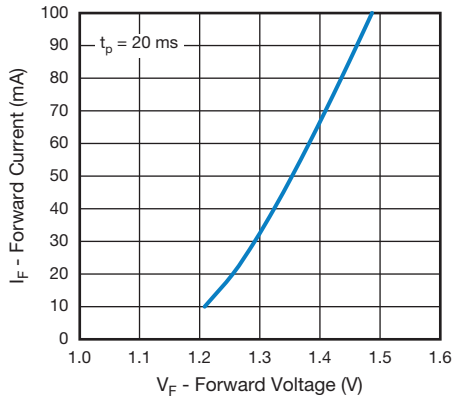


Fig. 4 - Forward Current vs. Forward Voltage

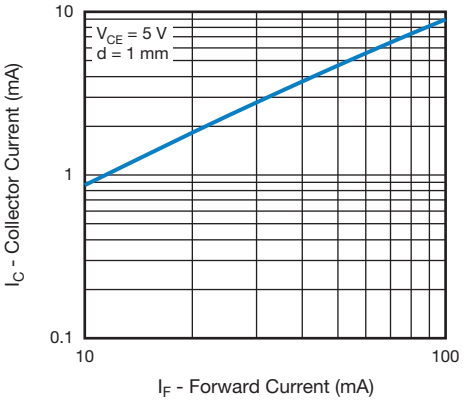


Fig. 7 - Collector Current vs. Forward Current

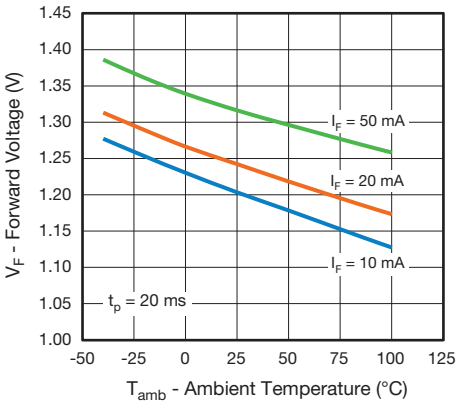


Fig. 5 - Forward Voltage vs. Ambient Temperature

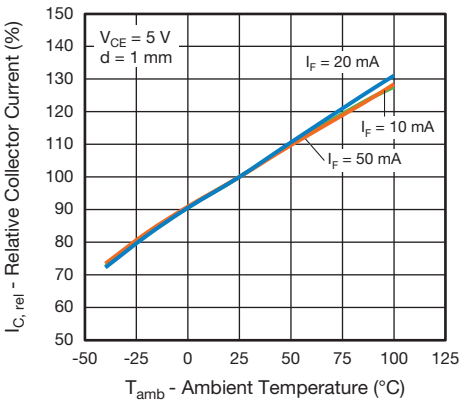


Fig. 8 - Relative Collector Current vs. Ambient Temperature

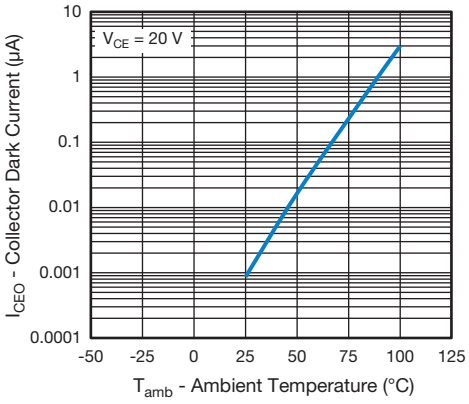


Fig. 6 - Collector Dark Current vs. Ambient Temperature

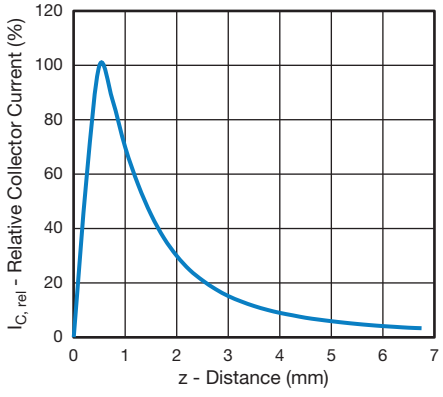


Fig. 9 - Relative Collector Current vs. Distance

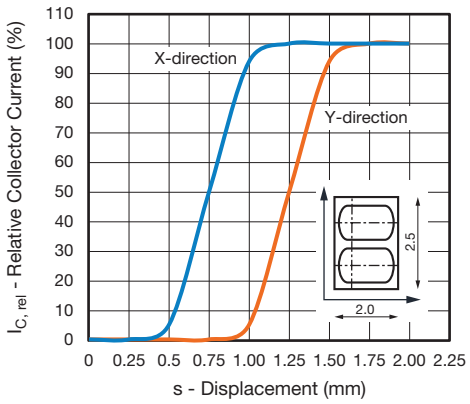


Fig. 10 - Relative Collector Current vs. Displacement

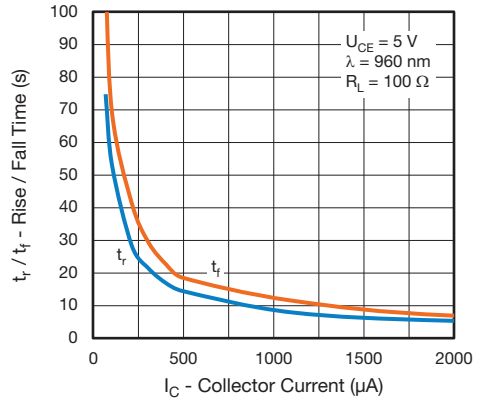


Fig. 11 - Rise / Fall Time vs. Collector Current

FLOOR LIFE

Time between soldering and removing from MBB must not exceed the time indicated in J-STD-020:

Moisture sensitivity: level 4

Floor life: 72 h

Conditions: T_{amb} < 30 °C, RH < 60 %

DRYING

In case of moisture absorption devices should be baked before soldering. Conditions see J-STD-020 or recommended conditions:

192 h at 40 °C (+ 5 °C), RH < 5 %
or
96 h at 60 °C (+ 5 °C), RH < 5 %

REFLOW SOLDER PROFILE

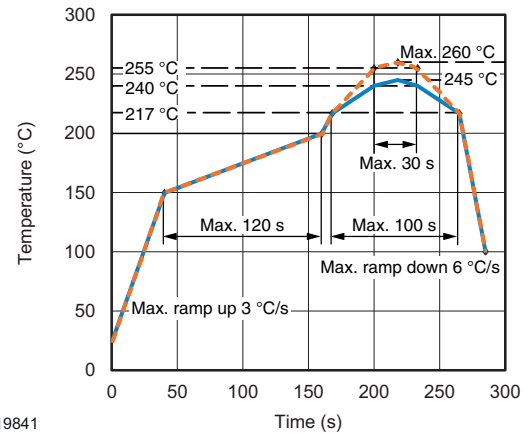
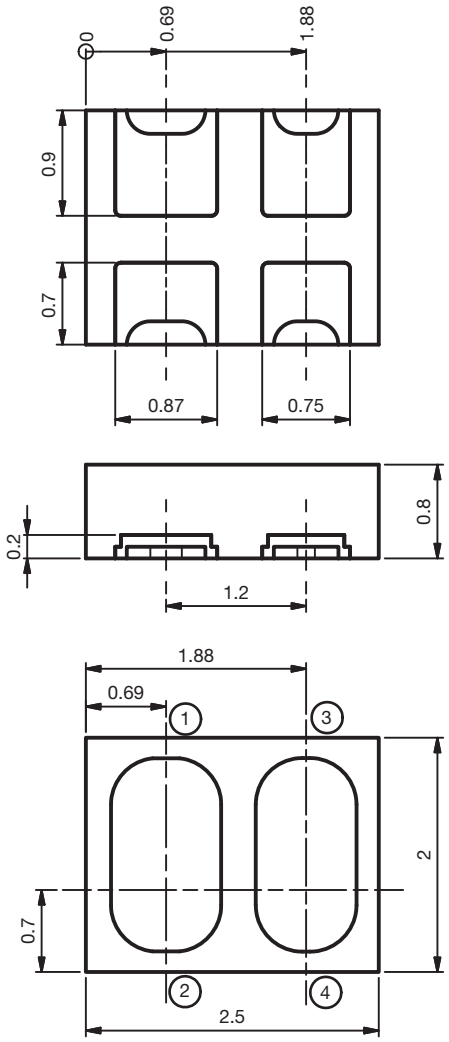
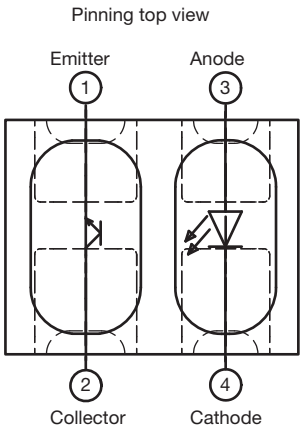
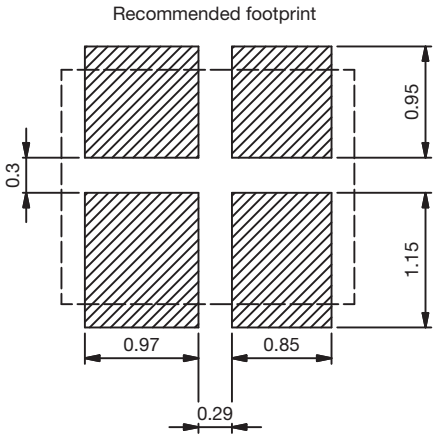


Fig. 12 - Lead (Pb)-free Reflow Solder Profile
According to J-STD-020

PACKAGE DIMENSIONS in millimeters







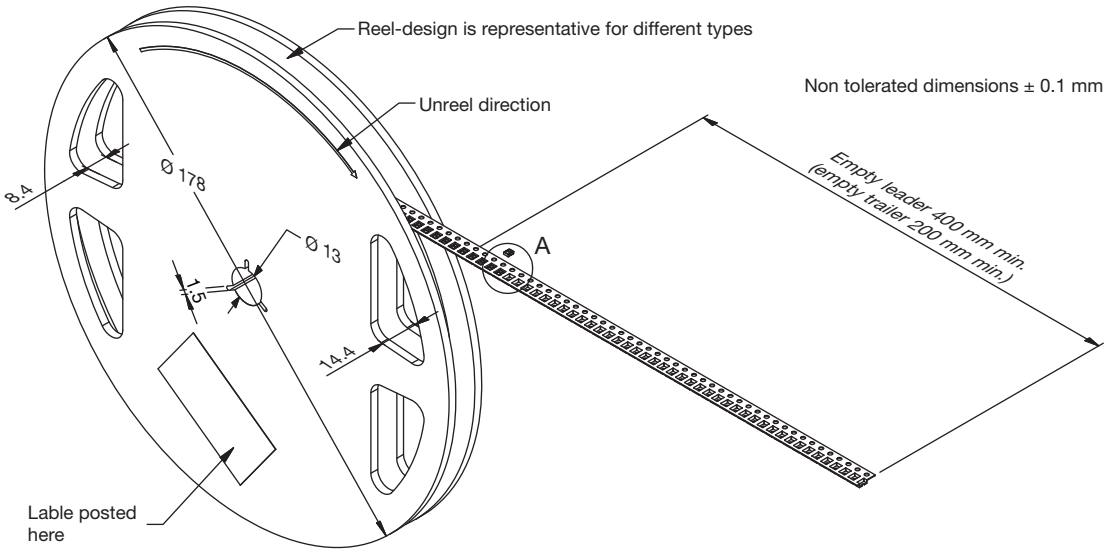
Drawing-No.: 6.550-5338.01-4
Issue: 1; 16.06.2016

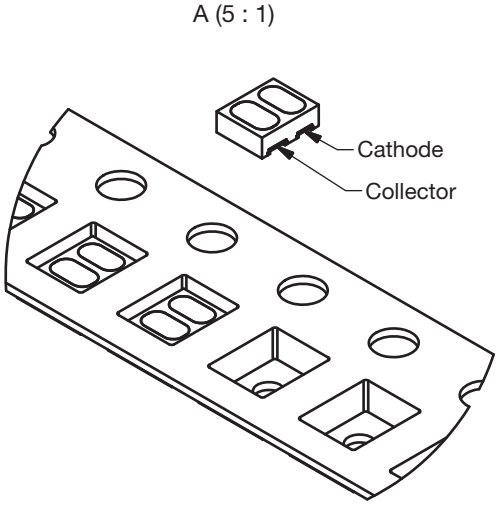
Not indicated tolerances ± 0.1

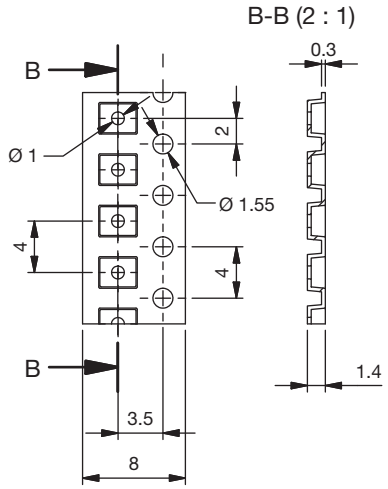
Technical drawings according to DIN specification

TAPE AND REEL DIMENSIONS in millimeters

3000 pcs/reel







Drawing refers to following Type: VCNT2020
Drawing No.: 9.800-5132.01-4
Issue: 1; 18.01.2018

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